Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 7; Fig. 8		-	-	50	mA
Dynamic	characteristics						
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 804 V; T_j = 125 °C; R_{GK} = 100 Ω; $(V_{DM}$ = 67% of V_{DRM}); exponential waveform		1500	-	-	V/µs

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		A
2	А	anode		G G
3	G	gate		sym037
mb	A	mounting base; connected to anode	1 2 3	

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity		Package issue date
BT155W-1200T	TO247	BT155W-1200TQ	Tube	30	TO247N	20-July-2016

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		1200	V
V_{RRM}	repetitive peak reverse voltage		1200	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 131 °C	50	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{mb} \le 131 ^{\circ}\text{C}$; Fig 1; Fig 2; Fig 3	79	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig 4; Fig 5	650	А
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	715	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	2113	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 200mA	150	A/µs
I _{GM}	peak gate current		8	А
V_{RGM}	peak reverse gate voltage		5	V
P_GM	peak gate power		20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	1	W
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		150	°C

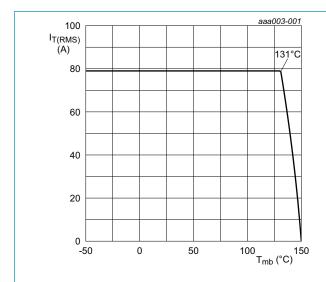
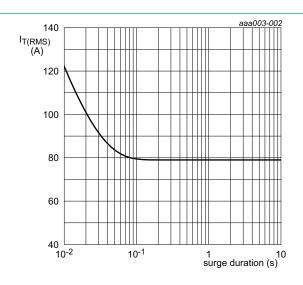
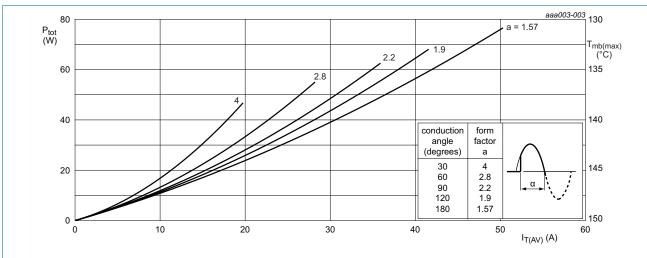


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values



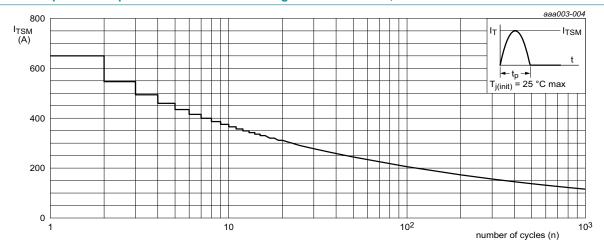
f = 50 Hz; T_{mb} = 131 °C Fig. 2. RMS on-state current as a function of surge duration; maximum values



 α = conduction angle

a = form factor = $I_{T(RMS)}$ / $I_{T(AV)}$

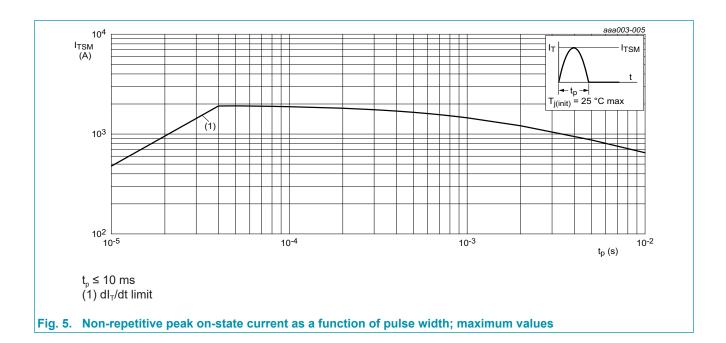
Fig. 3. Total power dissipation as a function of average on-state current; maximum values



f = 50 Hz

Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum

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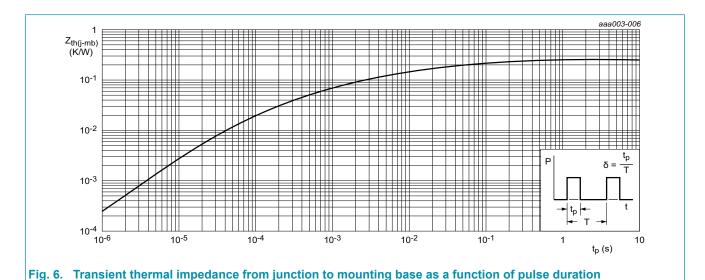


8. Thermal & Mechanical characteristics

Table 5. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig 6</u>	-	-	0.25	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W
	Mounting torque	M3 screw mounting	0.55	-	0.8	Nm

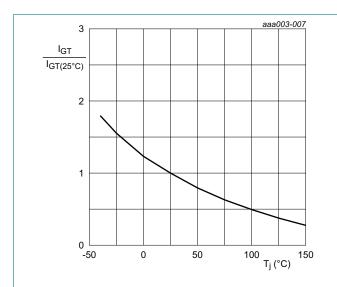
Note: It is recommended that a metal washer is inserted between screw head and mounting tab. Do not use self-tapping screws.



9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
l _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 7; Fig. 8	-	-	50	mA
I _L	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 9	-	-	300	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	200	mA
V _T	on-state voltage	I _T = 50 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.3	V
		I _T = 90 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.5	V
V_{GT}	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 12	-	0.7	1	V
		$V_D = 800 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C}$	0.25	0.4	-	V
I_D	off-state current	V _D = 1200 V; T _j = 125 °C	-	-	3	mA
I _R	reverse current	V _D = 1200 V; T _j = 125 °C	-	-	3	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 804 V; T_j = 125 °C; R_{GK} = 100 Ω; $(V_{DM}$ = 67% of V_{DRM}); exponential waveform	1500	-	-	V/µs
		V_{DM} = 804 V; T_j = 150 °C; R_{GK} = 100 Ω; (V_{DM} = 67% of V_{DRM}); exponential waveform	1000	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 40 \text{ A}; V_D = 800 \text{ V}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu\text{s}; T_j = 25 °C$	-	2	-	μs
t _q	commutated turn-off time	$V_{DM} = 804 \text{ V; } T_j = 125 \text{ °C; } I_{TM} = 20 \text{ A; } V_R = 25 \text{ V; } (dI_T/dt)_M = 30 \text{ A/}\mu\text{s; } dV_D/dt = 50 \text{ V/}\mu\text{s; } R_{GK(ext)} = 100 \text{ k}\Omega\text{; } (V_{DM} = 67\% \text{ of } V_{DRM})$	-	150	-	μs



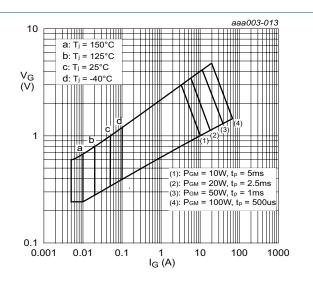
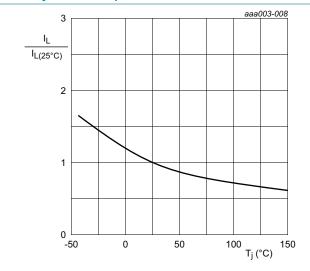


Fig. 7. Normalized gate trigger current as a function of junction temperature

Fig. 8. Gate voltage as a function of gate current



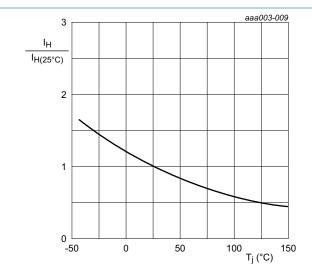
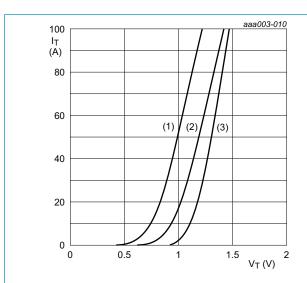


Fig. 9. Normalized latching current as a function of junction temperature

Fig. 10. Normalized holding current as a function of junction temperature

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 $V_o = 0.975 \text{ V}; R_s = 0.0044 \Omega$

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) $T_i = 25$ °C; maximum values

Fig. 11. On-state current as a function of on-state voltage

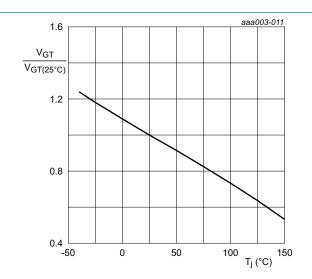
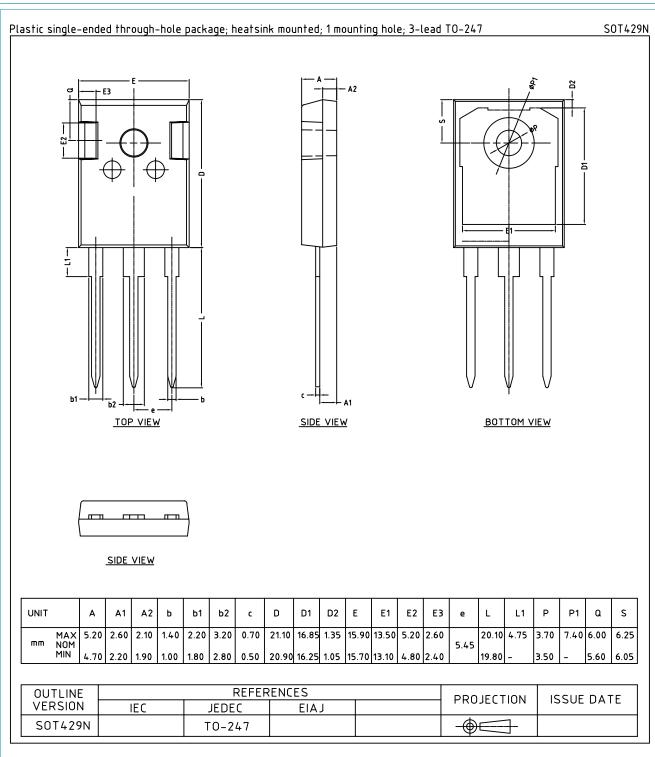


Fig. 12. Normalized gate trigger voltage as a function of junction temperature

10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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12. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Limiting values	3
8. Thermal characteristics	6
9. Characteristics	7
10. Package outline	10
11. Legal information	
12 Contents	

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